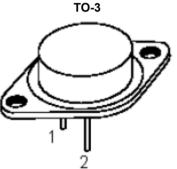


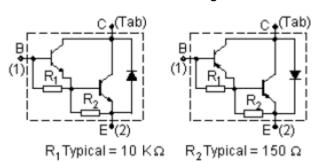


### **Description**

The MJ3001 is a silicon epitaxial-base NPN power transistors in monolithic darlington configuration and are mounted in JEDEC TO-3 metal case. They are intented for use in power linear and switching applications



#### **Internal Schematic Diagram**



## **Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit	
Collector-Base Voltage (I <sub>E</sub> = 0)	V <sub>CBO</sub>	00	V	
Collector-Emitter Voltage (I <sub>B</sub> = 0)	V <sub>CEO</sub>	- 80		
Emitter-Base Voltage (I <sub>C</sub> = 0)	V <sub>EBO</sub>	5		
Collector Current	I <sub>C</sub>	10		
Base Current	Ι <sub>Β</sub>	0.2	Α	
Total Dissipation at T <sub>c</sub> ≤25°C	P <sub>tot</sub>	150	W	
Storage Temperature	T <sub>stg</sub>	-65 to 200		
Maximum Operating Junction Temperature	T <sub>j</sub>	200	°C	

### **Thermal Characteristics**

Maximum Thermal Resistance Junction-case	R <sub>thi-case</sub>	1.17	°C/W

# Electrical Characteristics (T<sub>case</sub> = 25°C unless otherwise specified)

Parameter	Test Conditions	Symbol	Minimum	Maximum	Unit
Collector Cut-off Current ( $R_{BF} = 1 \text{ K}\Omega$ )	V <sub>CE</sub> = 80 V T <sub>case</sub> = 150°C	I <sub>CER</sub>	-	1	
,	VCE = 80 V	OLK		5	μΑ
Collector Cut-off Current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 30 V V <sub>CE</sub> = 40 V	I <sub>CEO</sub>	-	1 1	

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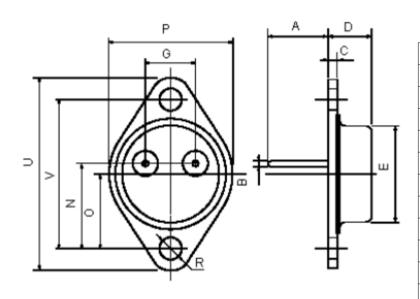




## Electrical Characteristics (T<sub>case</sub> = 25°C unless otherwise specified)

Parameter	Test Conditions	Symbol	Minimum	Maximum	Unit
Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V	I <sub>EBO</sub>	-	2	-
Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 100 mA	V <sub>CEO (sus)*</sub>	80	-	
Collector-Emitter Saturation Voltage	$I_C = 5 \text{ A}$ $I_B = 20 \text{ mA}$ $I_C = 10 \text{ A}$ $I_B = 50 \text{ mA}$	V <sub>CE (sat)*</sub>	-	2 4	V
Base-Emitter Voltage	I <sub>C</sub> = 5 A V <sub>CE</sub> = 3 V	V <sub>BE*</sub>	-	3	
DC Current Gain	I <sub>C</sub> = 5 A V <sub>CE</sub> = 3 V	h <sub>FE*</sub>	1,000	-	-

<sup>\*</sup> Pulsed: Pulse Duration = 300µs, Duty Cycle 1.5%.



### **TO-3 Mechanical Data**

Dimensions	Minimum	Maximum
Α	11 (0.433)	13.1 (0.516)
В	0.97 (0.038)	1.15 (0.045)
С	1.5 (0.59)	1.65 (0.065)
D	8.32 (0.327)	8.92 (0.351)
E	19 (0.748)	20 (0.787)
G	10.7 (0.421)	11.1 (0.437)
N	16.5 (0.649)	17.2 (0.677)
Р	25 (0.984)	26 (1.023)
R	4 (0.157)	4.09 (0.161)
U	38.5 (1.515)	39.3 (1.547)
V	30 (1.187)	30.3 (1.193)

Dimensions: Inches (Millimetres)

### **Part Number Table**

Description	Part Number		
Darlington Transistor, TO-3	MJ3001		

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